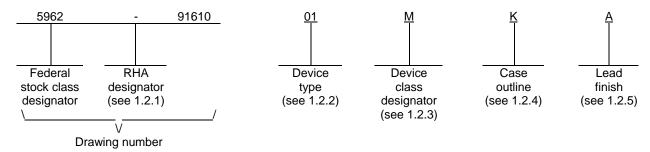
								F	REVISI	ONS										
LTR						DESCR	IPTIO						DA	ATE (YI	R-MO-I	DA)		APPF	ROVED	
А	Correct title to accurately describe device function. Add vendor CAGE 0C7V7. Update boilerplate to MIL-PRF-38535 requirements. Editorial changes throughout. – LTG								7V7.	06-08-01			<u>, , , , , , , , , , , , , , , , , , , </u>	Thomas M. Hess						
В	Corre	ect foot	note 4	in table	e I LT	G								07-0	1-24		Tho	mas M.	Hess	
REV				<u> </u>	1	<del></del>			1	1	<u> </u>			<u> </u>		1	1			
REV SHEET																				
	A																			
SHEET	A 15																			
SHEET REV	15			REV	/		В	A	A	A	A	A	В	A	A	A	A	A	A	A
SHEET REV SHEET	15			RE\ SHE			B 1	A 2	A 3	A 4	A 5	A 6	B 7	A 8	A 9	A 10	A 11	A 12	A 13	A 14
SHEET REV SHEET REV STATUS	15			SHE		D BY											-		-	
SHEET REV SHEET REV STATUS OF SHEETS	15			SHE	EET PAREI	D BY arcia B.	1	2			5	6	7	8	9	10	11	12	13	
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A	15			SHE	EET PAREI M	arcia B.	1	2			5	6 EFEN	7 SE SI	8 UPPL	9 Y CE	10	11 COL	12 _UMB	13	
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A STAI	NDAF OCIRO	CUIT		SHE	PAREI M	arcia B.	1 . Kelleh	2 ner			5	6 EFEN	7 SE SI	8	9 Y CE	10 NTER O 432	11 R COI 218-3	12 _UMB	13	
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A STAI	15	CUIT		SHE PRE	PAREI M	arcia B. BY	1 . Kelleh	2 ner			5	6 EFEN	7 SE SI	8 UPPL IBUS,	9 Y CE	10 NTER O 432	11 R COI 218-3	12 _UMB	13	
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A  STAI MICRO DRA  THIS DRAWIN FOR U DEPAI	NDAF OCIRC AWING NG IS A JSE BY / RTMEN	CUIT G VAILAI ALL TS		SHE PRE	PROVE	arcia B. BY	1 . Kelleh	2 ner uiti		MIC 9-B	DI CROC	EFEN CC	SE SI DLUM http	8 UPPL IBUS, o://ww	y CE, OHIO	NTER O 433 scc.dl	11 R COI 218-3 a.mil	12 -UMB 990	13	14
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A  STAI MICRO DRA  THIS DRAWIN FOR U	NDAF DCIRC AWING NG IS A JSE BY A JRTMEN NCIES C	CUIT G VAILAI ALL TS OF THE	≣	SHE PRE CHE	PAREI  CKED  The PROVE	BY nomas	1. Kelleh J. Ricco	2 ner uiti		MIC 9-B TRI TTL	DI DI CROC IT D GGE	EFEN CC CIRCU FLIP- RED MPAT	SE SI DLUM http JIT, [ -FLO , WIT	8 UPPL IBUS, D://ww DIGIT P, PC	Y CE, OHIO	10  ENTER O 432  GCC.dl	218-3 a.mil	12 -UMB 990	13 SUS MOS,	14
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A  STAI MICRO DRA  THIS DRAWIN FOR U DEPAI AND AGEN	NDAF DCIRC AWING NG IS A JSE BY A JRTMEN NCIES C	CUIT G VAILAI ALL TS OF THE	≣	SHE PRE CHE	PAREC M CCKED Th PROVE	BY nomas C D BY Michael	1. Kelleh J. Ricco	2 ner uiti		MIC 9-B TRI TTL SIL	DI CROC IT D GGE COI	EFEN CC CIRCU FLIP- RED MPAT	SE SI DLUM http JIT, [ -FLO , WIT	BUPPLIBUS, DIGIT P, PC	Y CE, OHIO	10  ENTER O 432  GCC.dl	218-3 a.mil	LUMB 990 ED CN	13 SUS MOS,	14
SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A  STAI MICRO DRA  THIS DRAWIN FOR U DEPAI AND AGEN DEPARTMEN	NDAF DCIRC AWING NG IS A JSE BY A JRTMEN NCIES C	CUIT G VAILAI ALL TS DF THE DEFEN	≣	SHE PRE CHE	PAREC M CCKED Th PROVE	BY nomas C D BY Michael APPRC	1. Kelleh J. Ricco A. Fry	2 ner uiti		MIC 9-B TRI TTL SIL	DI CROC IT D GGE COI ICON	EFEN CC CIRCU FLIP- RED MPAT I	FLO, WIT	BUPPLIBUS, DIGITP, PC	Y CE, OHIO	ADVA	ANCE	LUMB 990 ED CN	MOS,	14

## 1. SCOPE

- 1.1 <u>Scope</u>. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.
  - 1.2 PIN. The PIN is as shown in the following example:



- 1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
  - 1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function
01	54ACT823	9-bit D flip-flop, positive edge triggered, with three-state outputs, TTL compatible inputs

1.2.3 <u>Device class designator</u>. The device class designator is a single letter identifying the product assurance level as follows:

<u>Device class</u> <u>Device requirements documentation</u>

Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A

Q or V Certification and qualification to MIL-PRF-38535

1.2.4 <u>Case outline(s)</u>. The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
К	GDFP2-F24 or CDFP3-F24	24	Flat pack
L	GDIP3-T24 or CDIP4-T24	24	Dual-in-line
3	CQCC1-N28	28	Square leadless chip carrier

1.2.5 <u>Lead finish</u>. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

STANDARD
MICROCIRCUIT DRAWING

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990

SIZE <b>A</b>		5962-91610
	REVISION LEVEL A	SHEET 2

M

1.3 Absolute maximum ratings. 1/ 2/	
Supply voltage range $(V_{CC})$	0.5 V dc to $V_{CC}$ + 0.5 V dc0.5 V dc to $V_{CC}$ + 0.5 V dc±20 mA±50 mA±50 mA65°C to +150°C500 mW+300°C See MIL-STD-1835
1.4 Recommended operating conditions. 2/ 4/	
Supply voltage range (V <sub>CC</sub> )  Input voltage range (V <sub>IN</sub> )  Output voltage range (V <sub>OUT</sub> )  Case operating temperature range (T <sub>C</sub> )  Input rise or fall times:	+0.0 V dc to V <sub>CC</sub> +0.0 V dc to V <sub>CC</sub>
$V_{CC}$ = 4.5 V to 5.5 V	3.5 ns
$T_{C}$ = -55°C, +12 <u>5</u> °C, $V_{CC}$ = 4.5 V	3.5 ns
Minimum hold time, Dn to CP ( $t_{h1}$ ): $T_C = +25^{\circ}C$ , $V_{CC} = 4.5 \text{ V}$ $T_C = -55^{\circ}C$ , $+125^{\circ}C$ , $V_{CC} = 4.5 \text{ V}$	2.5 ns
Minimum hold time, $\overline{EN}$ to CP ( $t_{h2}$ ): $T_C = +25^{\circ}C$ , $V_{CC} = 4.5 \text{ V}$ $T_C = -55^{\circ}C$ , $+125^{\circ}C$ , $V_{CC} = 4.5 \text{ V}$	2.5 ns
Minimum CP pulse width, high, low ( $t_{w1}$ ): $T_C = +25^{\circ}C, V_{CC} = 4.5 \text{ V} \dots$ $T_C = -55^{\circ}C, +125^{\circ}C, V_{CC} = 4.5 \text{ V} \dots$ Minimum $\overline{CLR}$ pulse width ( $t_{w2}$ ):	
T <sub>C</sub> = +25°C, V <sub>CC</sub> = 4.5 V	
$T_C = +25^{\circ}C$ , $V_{CC} = 4.5 \text{ V}$	
$T_C = +25^{\circ}C$ , $V_{CC} = 4.5 \text{ V}$	

<sup>&</sup>lt;u>4/</u> The limits for the parameters specified herein shall apply over the full specified V<sub>CC</sub> range and case temperature range of -55°C to +125°C.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990		REVISION LEVEL A	SHEET 3

<sup>1/</sup> Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

<sup>2/</sup> Unless otherwise specified, all voltages are referenced to GND.

<sup>3/</sup> Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions per method 5004 of MIL-STD-883.

#### 2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

#### DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

#### DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

#### DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at http://assist.daps.dla.mil/quicksearch/ or http://assist.daps.dla.mil or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

#### 3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.
  - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.
  - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
  - 3.2.3 Truth table. The truth table shall be as specified on figure 2.
  - 3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.
  - 3.2.5 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified on figure 4.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990		REVISION LEVEL A	SHEET 4

- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.
- 3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.
- 3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change for device class M</u>. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.
- 3.9 <u>Verification and review for device class M.</u> For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 38 (see MIL-PRF-38535, appendix A).

STANDARD
MICROCIRCUIT DRAWING

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990

SIZE <b>A</b>		5962-91610
	REVISION LEVEL A	SHEET 5

TABLE I. <u>Electrical performance characteristics</u>.

Test	Symbol	Condit $-55^{\circ}\text{C} \leq \text{T}_{\text{C}}:$ $+4.5 \text{ V} \leq \text{V}_{\text{C}}$ unless otherwi	Group A subgroups	Device type		nits	Unit	
	1,,	,,	1,, 45,4	1 2 0		Min	Max	<u> </u>
High level output voltage 1/	V <sub>OH</sub>	$V_{IN} = V_{IH} min$ or $V_{IL} max$	$V_{CC} = 4.5 \text{ V}$	1, 2, 3	All	4.4		V
		I <sub>OH</sub> = -50 μA	$V_{CC} = 5.5 \text{ V}$			5.4		
		V <sub>IN</sub> = V <sub>IH</sub> min or V <sub>IL</sub> max	V <sub>CC</sub> = 4.5 V			3.7		
		$I_{OH} = -24 \text{ mA}$	$V_{CC} = 5.5 \text{ V}$			4.7		
		$V_{IN} = V_{IH} \text{ min}$ or $V_{IL} \text{ max}$ $I_{OH} = -50 \text{ mA}$	V <sub>CC</sub> = 5.5 V			3.85		
Low level output	V <sub>OL</sub>	$V_{IN} = V_{IH} \min$	V <sub>CC</sub> = 4.5 V	1, 2, 3	All		0.1	V
voltage <u>1</u> /		or $V_{IL}$ max $I_{OL} = 50 \mu A$	$V_{CC} = 5.5 \text{ V}$				0.1	
		V <sub>IN</sub> = V <sub>IH</sub> min or V <sub>IL</sub> max	V <sub>CC</sub> = 4.5 V				0.5	
		I <sub>OL</sub> = 24 mA	$V_{CC} = 5.5 \text{ V}$				0.5	
		$V_{IN} = V_{IH} \text{ min}$ or $V_{IL} \text{ max}$ $I_{OL} = 50 \text{ mA}$	$V_{CC} = 5.5 \text{ V}$				1.65	
High level input	V <sub>IH</sub>		V <sub>CC</sub> = 4.5 V	1, 2, 3	All	2.0		V
voltage <u>2</u> /			$V_{CC} = 5.5 \text{ V}$			2.0		
Low level input	V <sub>IL</sub>		$V_{CC} = 4.5 \text{ V}$	1, 2, 3	All		0.8	V
voltage <u>2/</u> Input leakage current,	I <sub>IL</sub>	V <sub>IN</sub> = 0.0 V	$V_{CC} = 5.5 \text{ V}$	1 2 2	All		-1.0	^
low	IIL	V <sub>IN</sub> = 0.0 V	V <sub>CC</sub> = 5.5 V	1, 2, 3	All		-1.0	μΑ
Input leakage current, high	I <sub>IH</sub>	$V_{IN} = 5.5 \text{ V}$					+1.0	μΑ
Quiescent supply current, outputs high	Іссн	$V_{IN} = V_{CC}$ or GND $V_{CC} = 5.5 \text{ V}$		1, 2, 3	All		160	μА
Quiescent supply current, outputs low	I <sub>CCL</sub>	I <sub>OUT</sub> = 0.0 V					160	μА
Quiescent supply current, outputs three-state	I <sub>CCZ</sub>						160	μΑ
Maximum I <sub>CC</sub> /input supply current 3/	$\Delta I_{CC}$	$V_{CC} = 5.5 \text{ V}$ Input under test = other inputs = $V_{C}$		1, 2, 3	All		1.6	mA
Three-state output leakage current, high	I <sub>OZH</sub>	$\overline{\text{OE}} = \text{V}_{\text{IH}} \text{ min or V}_{\text{I}}$ $\text{V}_{\text{OUT}} = 5.5 \text{ V}, \text{V}_{\text{CC}} = 1.0 \text{ All other inputs} = 1.0 \text{ V}_{\text{CC}}$	= 5.5 V	1, 2, 3	All		+10.0	μА
Three-state output leakage current, low	I <sub>OZL</sub>	$\overline{OE}$ = V <sub>IH</sub> min or V <sub>I</sub> V <sub>OUT</sub> = GND, V <sub>CC</sub> = All other inputs = V	= 5.5 V				-10.0	μА

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990		REVISION LEVEL A	SHEET 6

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions $-55^{\circ}C \le T_{C} \le +125^{\circ}C$ $+4.5 \ V \le V_{CC} \le +5.5 \ V$		Group A subgroups	Device	Limits		Unit
-		unless otherwise	specified	subgroups	type	Min	Max	
Input capacitance	C <sub>IN</sub>	See 4.4.1c		4	All		4.5	pF
Output capacitance	C <sub>OUT</sub>	See 4.4.1c		4	All		4.5	pF
Power dissipation capacitance <u>4</u> /	C <sub>PD</sub>	See 4.4.1c		4	All		4.4	pF
Functional tests		Tested at $V_{CC} = 4.5 \text{ V}$ are repeated at $V_{CC} = 5.5$ See 4.4.1d		7, 8	All			_
Propagation delay	t <sub>PHL1</sub>	C <sub>L</sub> = 50 pF minimum	$V_{CC} = 4.5 \text{ V}$	9	All	1.0	9.5	ns
time, CP to On 5/		$R_L = 500\Omega$		10, 11		1.0	12.0	
	t <sub>PLH1</sub>	See figure 4	$V_{CC} = 4.5 \text{ V}$	9		1.0	10.0	
				10, 11		1.0	12.0	
Propagation delay	t <sub>PHL2</sub>		$V_{CC} = 4.5 \text{ V}$	9	All	1.0	14.5	ns
time, CLR to On 5/				10, 11		1.0	18.0	
Propagation delay	t <sub>PZH</sub>		$V_{CC} = 4.5 \text{ V}$	9	All	1.0	9.5	ns
time, output enable,				10, 11		1.0	11.5	
OE to On 5/	t <sub>PZL</sub>		$V_{CC} = 4.5 \text{ V}$	9		1.0	10.0	
				10, 11		1.0	12.0	
Propagation delay	t <sub>PHZ</sub>		$V_{CC} = 4.5 \text{ V}$	9	All	1.0	12.0	ns
time, out <u>put</u> disable, OE to On				10, 11		1.0	13.5	
<u>5</u> /	t <sub>PLZ</sub>		$V_{CC} = 4.5 \text{ V}$	9		1.0	9.5	
				10, 11		1.0	12.0	

- $1/V_{OH}$  and  $V_{OL}$  tests will be tested at  $V_{CC}$  = 4.5 V.  $V_{OH}$  and  $V_{OL}$  are guaranteed, if not tested, for  $V_{CC}$  = 5.5 V. Limits shown apply to operation at  $V_{CC}$  = 5.0 V  $\pm$ 0.5 V. Transmission driving tests are performed at  $V_{CC}$  = 5.5 V with a 2 ms duration maximum.
- $\underline{2}$ /  $V_{IH}$  and  $V_{IL}$  tests are not required if applied as a forcing function for the  $V_{OH}$  and  $V_{OL}$  tests.
- $3/\Delta I_{CC}$  (max)/pin  $\leq$  1.6 mA (preferred method), or  $\Delta I_{CC}$ /package  $\leq$  1.6 mA x the number of input pins/package where  $\Delta I_{CC}$  (max)/data pin  $\leq$  1.6 mA and  $\Delta I_{CC}$  (max)/control pin  $\leq$  3.0 mA (alternate method).
- 4/ Power dissipation capacitance (C<sub>PD</sub>) determines both the dynamic power consumption (P<sub>D</sub>) and the dynamic current consumption (I<sub>S</sub>). Where:

$$\mathsf{P}_\mathsf{D} = (\mathsf{C}_\mathsf{PD} + \mathsf{C}_\mathsf{L}) \; (\mathsf{V}_\mathsf{CC} \; \mathsf{x} \; \mathsf{V}_\mathsf{CC}) \mathsf{f} \; + \; (\mathsf{I}_\mathsf{CC} \; \mathsf{x} \; \mathsf{V}_\mathsf{CC}) \; + \; (\mathsf{n} \; \mathsf{x} \; \mathsf{d} \; \mathsf{x} \; \Delta \mathsf{I}_\mathsf{CC} \; \mathsf{x} \; \mathsf{V}_\mathsf{CC})$$

$$I_S = (C_{PD} + C_L) V_{CC} f + I_{CC} + (n x d x \Delta I_{CC})$$

For both  $P_D$  and  $I_S$ , n is number of device inputs at TTL levels; f is the frequency of the input signal; d is duty cycle of the input signal; and  $C_L$  is the external output load capacitance.

 $\underline{5}$ / AC limits at V<sub>CC</sub> = 5.5 V are equal to the limits at V<sub>CC</sub> = 4.5 V and guaranteed by testing at V<sub>CC</sub> = 4.5 V. Minimum ac limits for V<sub>CC</sub> = 5.5 V are 1.0 ns and guaranteed by guardbanding the V<sub>CC</sub> = 4.5 V minimum limits to 1.5 ns.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE <b>A</b>		5962-91610
		REVISION LEVEL B	SHEET 7

Device type	All	
Case outlines	K and L	3
Terminal number	Terminal symbol	Terminal symbol
	Terminal symbol  OE  D0  D1  D2  D3  D4  D5  D6  D7  D8  CLR  GND	
14 15 16 17 18 19 20 21 22 23 24 25 26 27 28	CP EN O8 O7 O6 O5 O4 O3 O2 O1 O0 V <sub>CC</sub> 	GND NC CP EN O8 O7 O6 O5 NC O4 O3 O2 O1 O0 V <sub>CC</sub>

NC = No connection

Terminal symbol	Description
D0 – D8	Data inputs
O0 – O8	Data outputs
ŌĒ	Output enable
CLR	Clear
СР	Clock input
EN	Clock enable

FIGURE 1. <u>Terminal connections</u>.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990		REVISION LEVEL A	SHEET 8

		Inputs			Outputs		Outpu	t function
ŌE	CLR	EN	CP	D	Internal Qn	External On	Internal	External
Н	X	L	<b>↑</b>	L	Н	Z	Load	High Z
Н	Х	L	<b></b>	Н	L	Z	Load	High Z
Н	L	Χ	Χ	Х	Н	Z	Clear	High Z
L	L	Χ	Χ	Χ	Н	L	Clear	Clear
Н	Н	Н	Χ	X	NC	Z	Hold	High Z
L	Н	Н	Χ	X	NC	NC	Hold	Hold
Н	Н	L	$\uparrow$	L	Н	Z	Load	High Z
Н	Н	L	<b>↑</b>	Н	L	Z	Load	High Z
L	Н	L	<b></b>	L	Н	L	Load	Load
L	Н	L	<b>↑</b>	Н	L	Н	Load	Load

H = High voltage level
L = Low voltage level
↑ = Low-to-high clock transition
Z = High impedance
X = Irrelevant

NC = No change

FIGURE 2. Truth table.

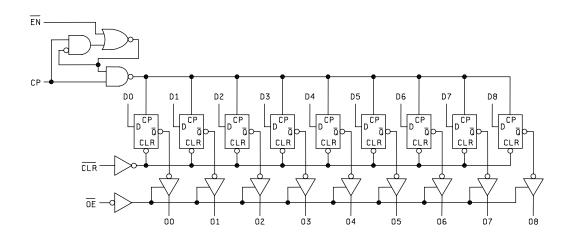
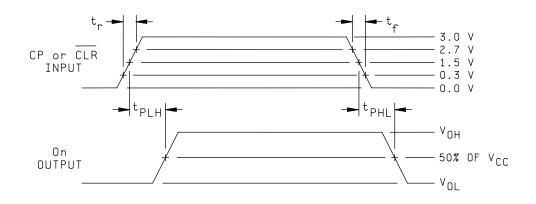


FIGURE 3. Logic diagram.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990		REVISION LEVEL A	SHEET 9



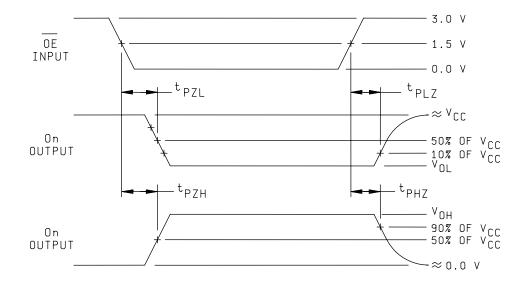


FIGURE 4. Switching waveforms and test circuit.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		A	10

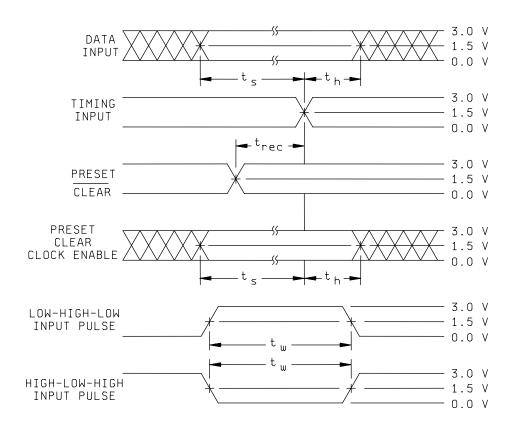
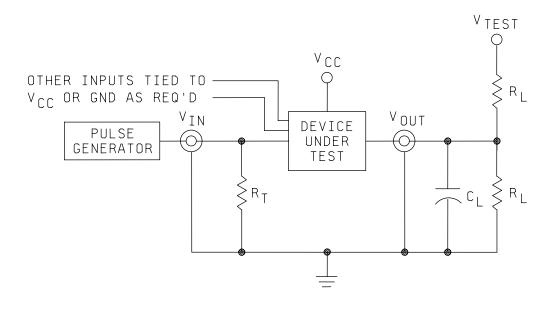


FIGURE 4. Switching waveforms and test circuit - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		A	11



# NOTES:

- 1. When measuring  $t_{PLZ}$  and  $t_{PZL}$ :  $V_{TEST} = 2 \times V_{CC}$ .
- 2. When measuring  $t_{PHZ}$ ,  $t_{PZH}$ ,  $t_{PLH}$ , and  $t_{PHL}$ ;
  - the preferred method is:  $V_{TEST} = GND$  for  $t_{PHZ}$  and  $t_{PZH}$  and open for  $t_{PLH}$  and  $t_{PHL}$ ; the alternate method is:  $V_{TEST} = Open$  for  $t_{PHZ}$ ,  $t_{PZH}$ ,  $t_{PLH}$ , and  $t_{PHL}$ .
- 3. The  $t_{PZL}$  and  $t_{PZL}$  reference waveform is for the output under test with internal conditions such that the output is at  $V_{OL}$ except when disabled by the output enable control. The  $t_{PZH}$  and  $t_{PHZ}$  reference waveform is for the output under test with internal conditions such that the output is at V<sub>OH</sub> except when disabled by the output enable control.
- 4.  $C_L = 50 \text{ pF}$  minimum or equivalent (includes test jig and probe capacitance).
- 5.  $R_L = 500\Omega$  or equivalent;  $R_T = 50\Omega$  or equivalent.
- 6. Input signal from pulse generator:  $V_{IN} = 0.0 \text{ V}$  to 3.0 V; PRR  $\leq$  1 MHz;  $t_r \leq$  3.0 ns;  $t_f \leq$  3.0 ns;  $t_r$  and  $t_f$  shall be measured from 0.3 V to 2.7 V and from 2.7 V to 0.3 V, respectively; duty cycle = 50 percent.
- 7. Timing parameters shall be tested at a minimum input frequency of 1 MHz.
- 8. The outputs are measured one at a time with one transition per measurement.

FIGURE 4. Switching waveforms and test circuit – Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE <b>A</b>		5962-91610
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990		REVISION LEVEL A	SHEET 12

## 4. VERIFICATION

- 4.1 <u>Sampling and inspection</u>. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.
  - 4.2.1 Additional criteria for device class M.
    - a. Burn-in test, method 1015 of MIL-STD-883.
      - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
      - (2)  $T_A = +125^{\circ}C$ , minimum.
    - b. Interim and final electrical test parameters shall be as specified in table II herein.
  - 4.2.2 Additional criteria for device classes Q and V.
    - a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
    - b. Interim and final electrical test parameters shall be as specified in table II herein.
    - c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.
- 4.3 Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

STANDARD				
MICROCIRCUIT DRAWING				

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990

SIZE <b>A</b>		5962-91610
	REVISION LEVEL A	SHEET 13

# 4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C<sub>IN</sub>, C<sub>OUT</sub>, and C<sub>PD</sub> measurements) shall be measured only for the initial test and after process or design changes which may affect capacitance. Test all applicable pins on 5 devices with zero failures.
- d. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table as specified on figure 2 herein. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.

TABLE II. Electrical test requirements.

Test requirements	Subgroups	Sub	groups
	(in accordance with	(in accor	dance with
	MIL-STD-883,	MIL-PRF-3	8535, table III)
	method 5005, table I)		
	Device	Device	Device
	class M	class Q	class V
Interim electrical		1	1
parameters (see 4.2)			
Final electrical	1, 2, 3, 7, 8, 9,	1, 2, 3, 7, 8, 9,	1, 2, 3, 7, 8, 9,
parameters (see 4.2)	10, 11 <u>1</u> /	10, 11 <u>1</u> /	10, 11 <u>2</u> /
Group A test	1, 2, 3, 4, 7, 8, 9,	1, 2, 3, 4, 7, 8,	1, 2, 3, 4, 7, 8,
requirements (see 4.4)	10, 11	9, 10, 11	9, 10, 11
Group C end-point electrical	1, 2, 3	1, 2, 3	1, 2, 3
parameters (see 4.4)			
Group D end-point electrical	1, 2, 3	1, 2, 3	1, 2, 3
parameters (see 4.4)			
Group E end-point electrical	1, 7, 9	1, 7, 9	1, 7, 9
parameters (see 4.4)			

<sup>1/</sup> PDA applies to subgroup 1.

- 4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:
  - a. Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
  - b.  $T_A = +125$ °C, minimum.
  - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE <b>A</b>		5962-91610
		REVISION LEVEL A	SHEET 14

<sup>2/</sup> PDA applies to subgroups 1 and 7.

- 4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
  - 4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).
  - a. End-point electrical parameters shall be as specified in table II herein.
  - b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at T<sub>A</sub> = +25°C ±5°C, after exposure, to the subgroups specified in table II herein.

## 5. PACKAGING

- 5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.
  - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
  - 6.1.2 Substitutability. Device class Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.
- 6.3 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990 or telephone (614) 692-0547.
- 6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.
  - 6.6 Sources of supply.
- 6.6.1 <u>Sources of supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.
- 6.6.2 <u>Approved sources of supply for device class M.</u> Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE <b>A</b>		5962-91610
		REVISION LEVEL A	SHEET 15

## STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 07-01-24

Approved sources of supply for SMD 5962-91610 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN <u>1</u> /	number	PIN <u>2</u> /
5962-9161001MKA	0C7V7	54ACT823FMQB
5962-9161001MLA	0C7V7	54ACT823SDMQB
5962-9161001M3A	0C7V7	54ACT823LMQB

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed, contact the vendor to determine its availability.
- <u>2</u>/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

 Vendor CAGE
 Vendor name

 number
 and address

0C7V7 QP Semiconductor

2945 Oakmead Village Court Santa Clara, CA 95051

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Flip Flops category:

Click to view products by E2v manufacturer:

Other Similar products are found below:

5962-8955201EA MC74HC11ADTG MC10EP29MNG MC74HC11ADTR2G NLV14013BDTR2G NLV14027BDG NLX1G74MUTCG
703557B 746431H 5962-90606022A 5962-9060602FA NLV14013BDR2G M38510/30104BDA M38510/07106BFA M38510/06101B2A NLV74HC74ADR2G TC4013BP(N,F) NLV14013BDG NLV74AC32DR2G NLV74AC74DR2G MC74HC73ADG
CY74FCT16374CTPACT MC74HC11ADR2G 74LVT74D,118 74VHCT9273FT(BJ) MM74HC374WM 74ALVCH162374PAG
TC7WZ74FK,LJ(CT CD54HCT273F HMC853LC3TR HMC723LC3CTR MM74HCT574MTCX MM74HCT273WM SN74LVC74APW
SN74LVC74AD MC74HC73ADTR2G MC74HC11ADG SN74ALVTH16374GR M74HCT273B1R M74HC377RM13TR
M74HC374RM13TR M74HC175B1R M74HC174RM13TR 74ALVTH16374ZQLR 74ALVTH32374ZKER 74AUP1G74DC,125
74VHC374FT(BJ) 74VHC9273FT(BJ) NLV14013BCPG